

SuperMOS – SOT23-6L -20V BV_{DSS} , 82m Ω $R_{DS(on)}$, P-channel MOSFET

1. Description

The DMP2240UDM-ES is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product DMP2240UDM-ES is Pb-free.

2. Features

- -20V, $R_{DS(ON)}$ =82m Ω (TYP.) @ V_{GS} =-4.5V
- $R_{DS(ON)}$ =118m Ω (TYP.) @ V_{GS} =-2.5V
- $R_{DS(ON)}$ =180m Ω (TYP.) @ V_{GS} =-1.8V
- Fast Switching
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
DMP2240UDM-ES	SOT23-6L	.6312P	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

5. Pin Configuration and Functions

Pin	Function	Outline	Circuit Diagram
1	Gate1		
5	Source1		
6	Drain1		
3	Gate2		
2	Source2		
4	Drain2		

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	BV_{DSS}	-20	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	$T_A=25^\circ C$	-2
		$T_A=100^\circ C$	-1.3
Maximum Power Dissipation	P_D	0.8	W
Pulsed Drain Current	I_{DM}	-8	A
Operating Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ C$

Thermal resistance ratings

Single Operation				
Parameter	Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance ($t \leq 10s$)	$R_{\theta JA}$		156	$^\circ C/W$

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-20			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$			-1	μA
Gate-to-source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 12V$			± 100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=-250\mu A$	-0.4	-0.62	-1.0	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-2A$		82	95	m Ω
		$V_{GS}=-2.5A, I_D=-1.5A$		118	138	
		$V_{GS}=-1.8V, I_D=-1A$		180	210	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C_{ISS}	$V_{GS}=0V, V_{DS}=-10V$ $f=1MHz$		185		pF
Output Capacitance	C_{OSS}			35		
Reverse Transfer Capacitance	C_{RSS}			25		
Total Gate Charge	Q_G	$V_{GS}=-4.5V, V_{DS}=-10V$ $I_D=-2A$		2.2		nC
Gate-to-Source Charge	Q_{GS}			0.5		
Gate-to-Drain Charge	Q_{GD}			0.5		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS}=-4.5V, V_{DS}=-10V$ $R_L=5\Omega, R_G=3\Omega$		10		ns
Rise Time	t_r			30		
Turn-Off Delay Time	$t_{d(OFF)}$			62		
Fall Time	t_f			50		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=-2A$			-1.5	V

7. Typical Characteristics

Figure 1: Output Characteristics

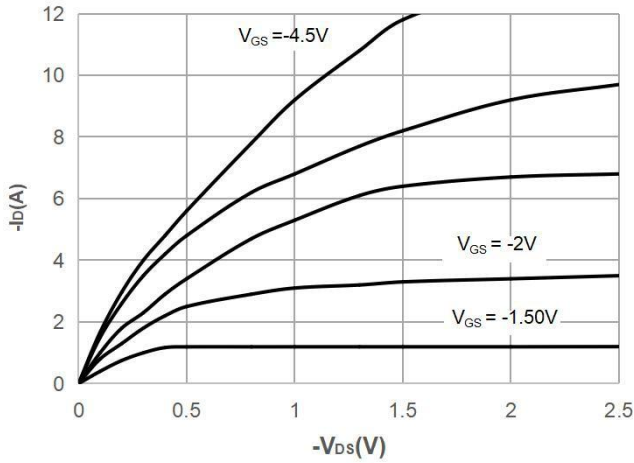


Figure 2: Typical Transfer Characteristics

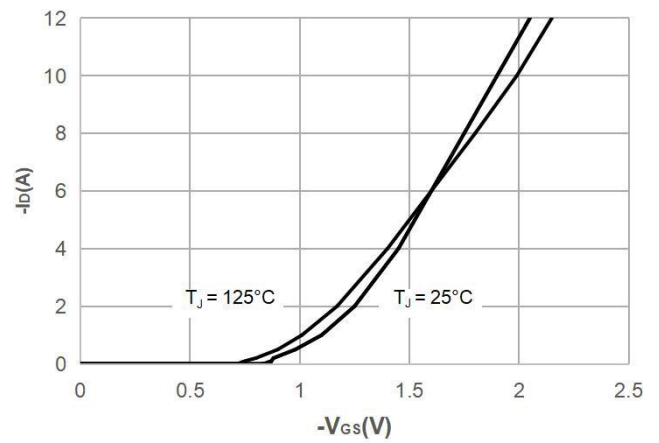


Figure 3: On-resistance vs. Drain Current

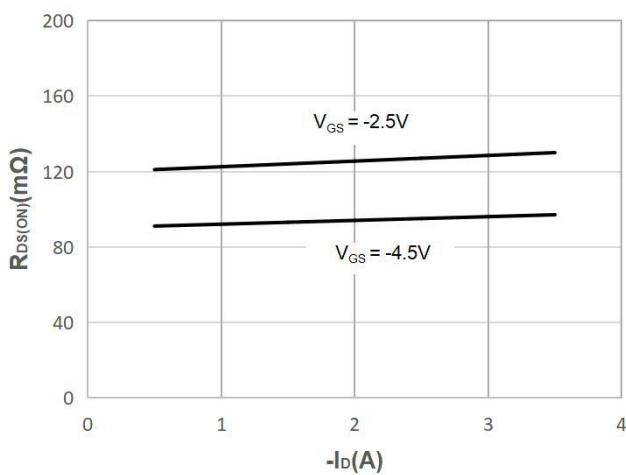


Figure 4: Body Diode Characteristics

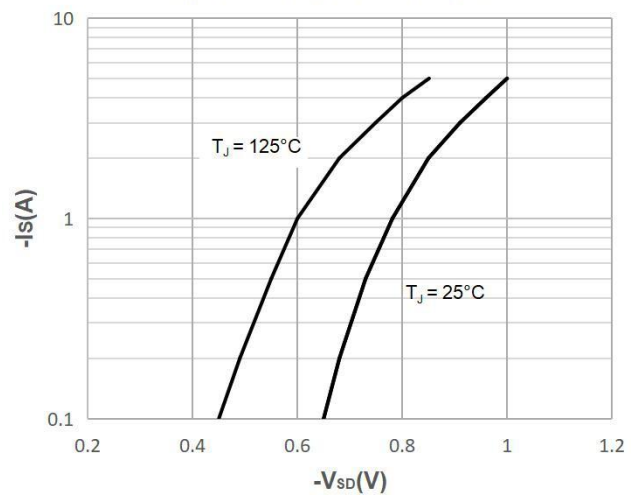


Figure 5: Gate Charge Characteristics

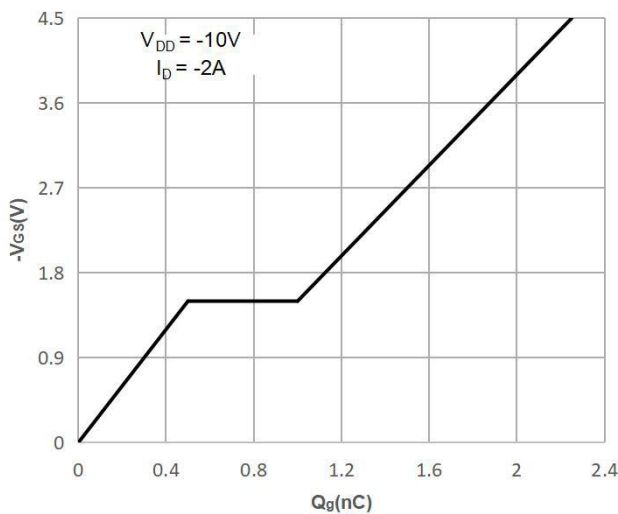


Figure 6: Capacitance Characteristics

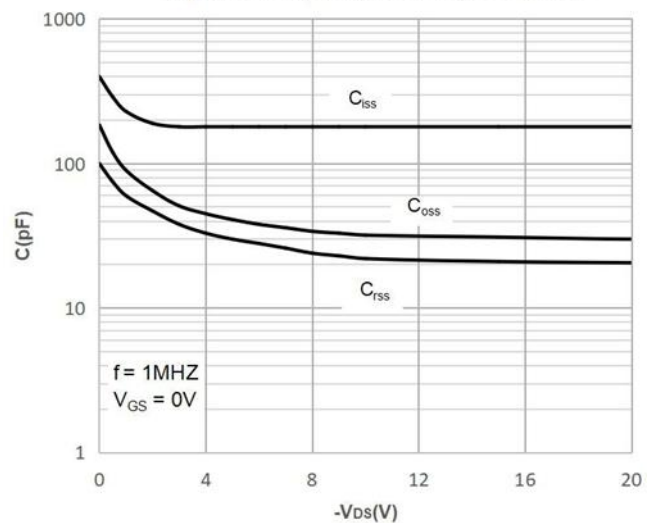


Figure 7: Normalized Breakdown voltage vs. Junction Temperature

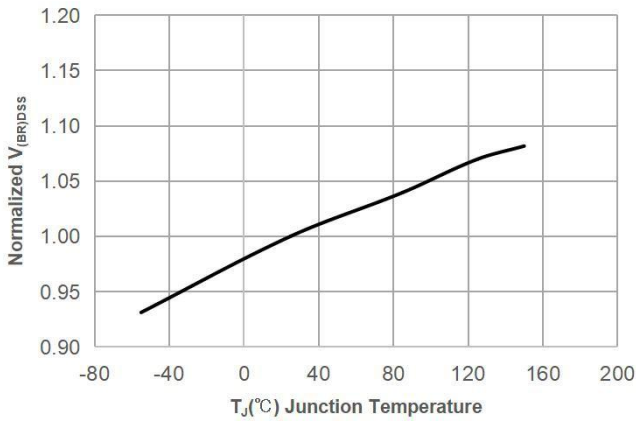


Figure 8: Normalized on Resistance vs. Junction Temperature

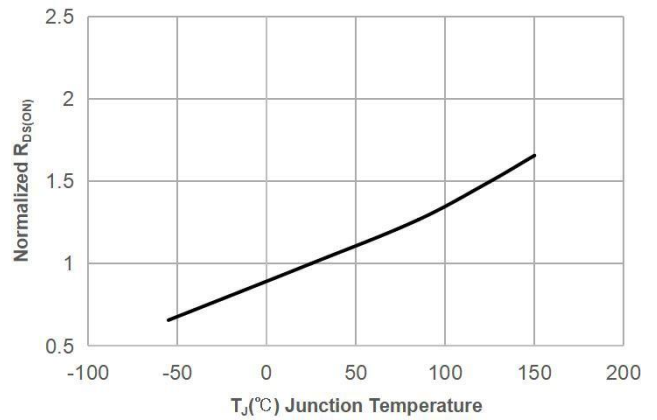


Figure 9: Maximum Safe Operating Area

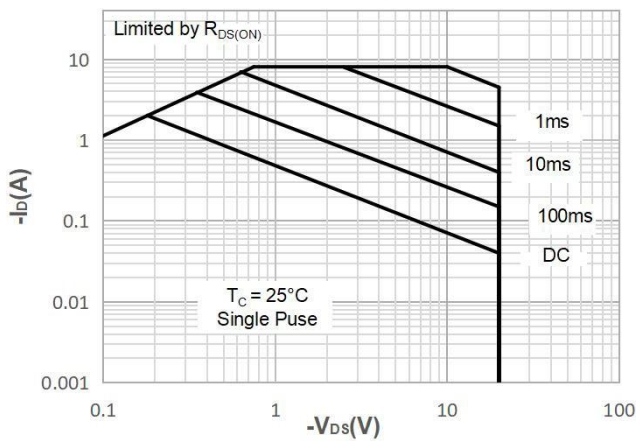


Figure 10: Maximum Continuous Driain Current vs. Case Temperature

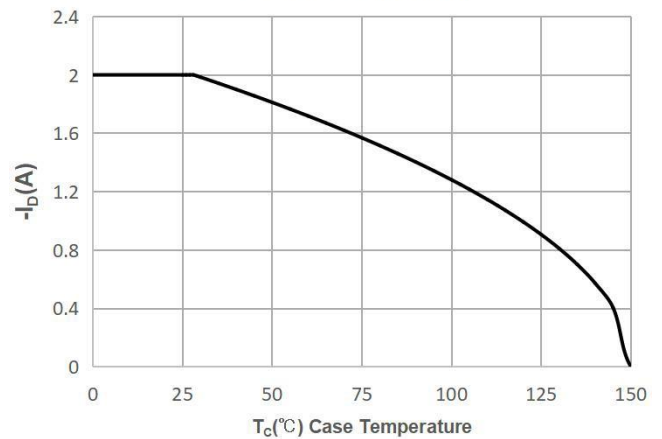


Figure 11: Normalized Maximum Transient Thermal Impedance

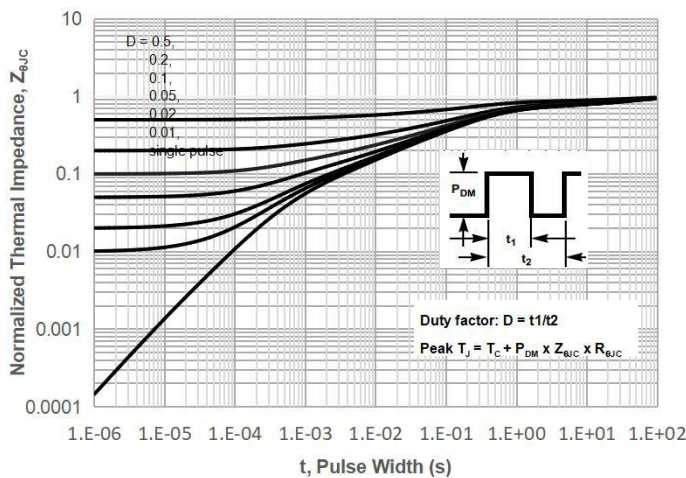
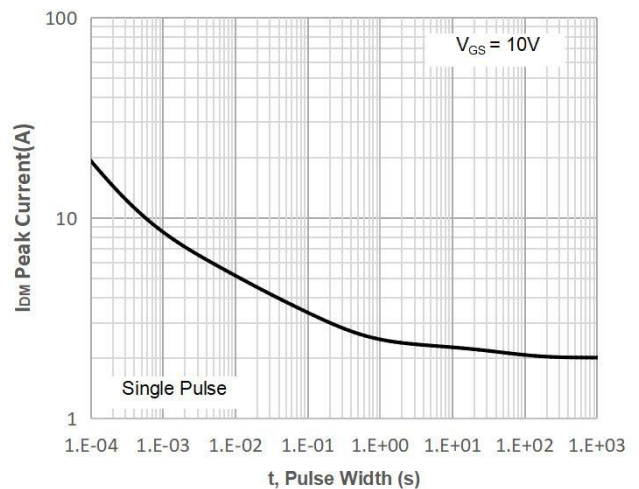


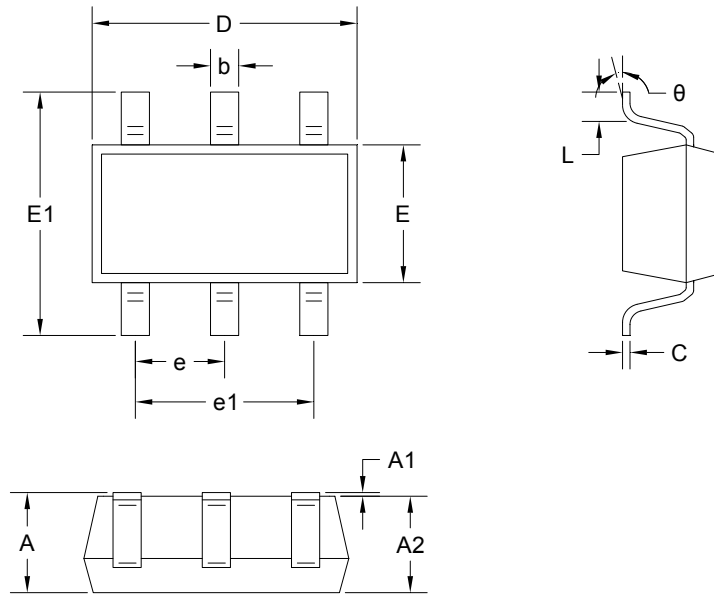
Figure 12: Peak Current Capacity



DMP2240UDM-ES

Rev-1.3

8. Dimension (SOT23-6L)



Unit: mm

Symbol		A	A1	A2	b	c	D
Spec	Min	1.050	0.000	1.050	0.300	0.100	2.820
	Max	1.250	0.100	1.150	0.500	0.200	3.020
Symbol		E	E1	e	e1	L	θ
Spec	Min	1.500	2.650	0.950BSC	1.800	0.300	0°
	Max	1.700	2.950		2.000	0.600	8°

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